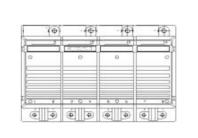
## SKiiP 832GB120-406CTV ...



## SKiiP<sup>®</sup> 2

## 2-pack - integrated intelligent Power System

**Power section** 

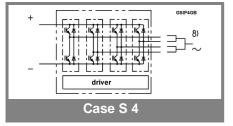
SKiiP 832GB120-406CTV

#### **Features**

- SKiiP technology inside
- Low loss IGBTs
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3k3/IE32 (SKiiP<sup>®</sup> 2 System)
- IEC 68T.1 (climate) 40/125/56 (SKiiP<sup>®</sup> 2 power section)
- with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)
- 8) AC connection busbars must be connected by the user; copper busbars available on request

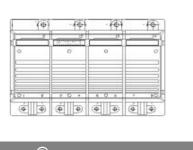
Absolute Maximum Ratings		$\Gamma_{\rm s}$ = 25 °C unless otherwise specified				
Symbol	Conditions	Values	Units			
IGBT						
$V_{CES}$		1200	V			
V <sub>CES</sub> V <sub>CC</sub> 1)	Operating DC link voltage	900	V			
$V_{GES}$		± 20	V			
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	800 (600)	Α			
Inverse diode						
$I_F = -I_C$	T <sub>s</sub> = 25 (70) °C	800 (600)	Α			
I <sub>FSM</sub>	$T_j = 150 ^{\circ}\text{C},  t_p = 10 \text{ms};  \text{sin}.$	5760	Α			
I <sup>2</sup> t (Diode)	Diode, T <sub>j</sub> = 150 °C, 10 ms	166	kA²s			
$T_j$ , $(T_{stg})$		- 40 (- 25) <b>+</b> 150 (125)	°C			
V <sub>isol</sub>	AC, 1 min. (mainterminals to heat sink)	3000	V			

Characteristics T <sub>s</sub> = 25 °C unless otherwise specifie								specified
Symbol   Conditions				s   min.	typ.	max.	Units	
IGBT	Conditio	113			111111.	ιyρ.	max.	Units
V <sub>CEsat</sub>	I <sub>C</sub> = 700 A,	T. = 25 (1	25) °C		İ	2,6 (3,1)	3,1	l v
V <sub>CEO</sub>	$T_i = 25 (125)$		20) 0			,	1,5 (1,6)	V
r <sub>CE</sub>	$T_i = 25 (125)$						2,3 (2,9)	mΩ
I <sub>CES</sub>	J					(40)	1.6	mA
CES	$V_{GE} = 0 \text{ V}, V_{CE} = V_{CES},$ $T_i = 25 (125) ^{\circ}C$					(10)	1,0	
E <sub>on</sub> + E <sub>off</sub>	I <sub>C</sub> = 700 A,	V <sub>CC</sub> = 60	0 V				210	mJ
on on	T <sub>j</sub> = 125 °C						370	mJ
R <sub>CC' + EE'</sub>	terminal chi	p, T <sub>i</sub> = 12	5 °C			0,13		mΩ
L <sub>CE</sub>	top, bottom	,				3,8		nΗ
C <sub>CHC</sub>	per phase,	AC-side				5,6		nF
Inverse o	diode							
$V_F = V_{EC}$	I <sub>F</sub> = 600 A,	T <sub>i</sub> = 25 (1	25) °C			2,1 (1,9)	2,6	V
$V_{TO}$	$T_i = 25 (125)$					1,3 (1)	1,4 (1,1)	V
$r_T$	$T_j = 25 (125)$					1,3 (1,5)	1,7 (2)	mΩ
E <sub>rr</sub>	$I_{\rm C} = 700  \text{A},$	$V_{CC} = 60$	0 V				24	mJ
	T <sub>j</sub> = 125 °C	$V_{CC} = 90$	00 V				31	mJ
Mechani	cal data							
M <sub>dc</sub>	DC termina	ls, SI Uni	ts		6		8	Nm
M <sub>ac</sub>	AC terminals, SI Units				13		15	Nm
w	SKiiP® 2 System w/o heat sink					3,5		kg
w	heat sink					8,5		kg
Thermal	character	istics (	P16 hea	t sink; 27	75m <sup>3</sup> /h);	", " refer	ence to	
•	ture sense	or			•	•		
$R_{th(j-s)I}$	per IGBT						0,032	K/W
$R_{th(j-s)D}$	per diode						0,094	K/W
$R_{th(s-a)}$	per module						0,033	K/W
$Z_{th}$	R <sub>i</sub> (mK/W) (				tau <sub>i</sub> (s)			
	1	2	3	4	1	2	3	4
$Z_{th(j-r)I}$	4	25	4		1	0,13	0,001	
$Z_{th(j-r)D}$	10	72	11		1	0,13	0,001	
$Z_{\text{th(r-a)}}$	1,6	22	7	2,4	494	165	20	0,03



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## SKiiP 832GB120-406CTV ...



#### SKiiP<sup>®</sup> 2

# 2-pack - integrated intelligent Power System

2-pack integrated gate driver

SKiiP 832GB120-406CTV

#### **Gate driver features**

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- · Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- · Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 68T.1 (climate) 25/85/56 (SKiiP<sup>®</sup> 2 gate driver)

Absolute Maximum Ratings					
Symbol	Conditions	Values	Units		
$V_{S1}$	stabilized 15 V power supply	18	V		
$V_{S2}$	unstabilized 24 V power supply	30	V		
$V_{iH}$	input signal voltage (high)	15 + 0,3	V		
dv/dt	secondary to primary side	75	kV/μs		
$V_{isollO}$	input / output (AC, r.m.s., 2s)	3000	Vac		
V <sub>isol12</sub>	output 1 / output 2 (AC, r.m.s., 2s)	1500	Vac		
$f_{max}$	switching frequency	19	kHz		
$T_{op} (T_{stg})$	operating / storage temperature	- 25 <b>+</b> 85	°C		

Characteristics (T <sub>a</sub>					= 25 °C)
Symbol	Conditions	min.	typ.	max.	Units
$V_{S1}$	supply voltage stabilized	14,4	15	15,6	V
$V_{S2}$	supply voltage non stabilized	20	24	30	V
I <sub>S1</sub>	V <sub>S1</sub> = 15 V	290+550	290+550*f/f <sub>max</sub> +1,3*(I <sub>AC</sub> /A)		
I <sub>S2</sub>	V <sub>S2</sub> = 24 V	220+400	220+400*f/f <sub>max</sub> +1,0*(I <sub>AC</sub> /A)		
$V_{iT+}$	input threshold voltage (High)	11,2			V
$V_{iT-}$	input threshold voltage (Low)			5,4	V
R <sub>IN</sub>	input resistance		10		kΩ
t <sub>d(on)IO</sub>	input-output turn-on propagation time		1,2		μs
t <sub>d(off)IO</sub>	input-output turn-off propagation time		1,6		μs
tpERRRESET	error memory reset time	9			μs
$t_{TD}$	top / bottom switch : interlock time		3,3		μs
I <sub>analogOUT</sub>	8 V corresponds to max. current of 15 V supply voltage		800		Α
I <sub>Vs1outmax</sub>	(available when supplied with 24 V)			50	mA
I <sub>A0max</sub>	output current at pin 12/14			5	mA
V <sub>0I</sub>	logic low output voltage			0,6	V
$V_{0H}$	logic high output voltage			30	V
I <sub>TRIPSC</sub>	over current trip level (I <sub>analog OUT</sub> = 10 V)		1000		Α
I <sub>TRIPLG</sub>	ground fault protection				Α
T <sub>tp</sub>	over temperature protection	110		120	°C
U <sub>DCTRIP</sub>	trip level of U <sub>DC</sub> -protection	900			V
	( U <sub>analog OUT</sub> = 9 V); (option)				

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